

2SJ473-01S-VB Datasheet

P-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY

| V_{DS} (V) | $R_{DS(on)}$ (Ω) | I_D (A) | Q_g (Typ) |
|--------------|-----------------------------|-----------|-------------|
| - 60 | 0.061 at $V_{GS} = - 10$ V | - 30 | 10 |
| | 0.072 at $V_{GS} = - 4.5$ V | - 25 | |

FEATURES

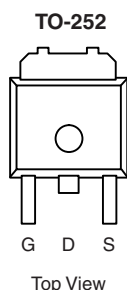
- Trench Power MOSFET
- 100 % UIS Tested

APPLICATIONS

- Load Switch



RoHS
COMPLIANT
HALOGEN
FREE



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted

| Parameter | | Symbol | Limit | Unit |
|--|-----------------------------------|----------------|-----------------|------------------|
| Gate-Source Voltage | | V_{GS} | ± 20 | V |
| Continuous Drain Current ($T_J = 175\text{ }^\circ\text{C}$) | $T_C = 25\text{ }^\circ\text{C}$ | I_D | - 30 | A |
| | $T_C = 100\text{ }^\circ\text{C}$ | | - 25 | |
| Pulsed Drain Current | | I_{DM} | - 30 | |
| Continuing Source Current (Diode Conduction) | | I_S | - 20 | |
| Avalanche Current | | I_{AS} | - 20 | |
| Single Pulse Avalanche Energy | $L = 0.1\text{ mH}$ | E_{AS} | 7.2 | mJ |
| Maximum Power Dissipation | $T_C = 25\text{ }^\circ\text{C}$ | P_D | 34 ^a | W |
| | $T_A = 25\text{ }^\circ\text{C}$ | | 4 ^b | |
| Operating Junction and Storage Temperature Range | | T_J, T_{stg} | - 55 to 175 | $^\circ\text{C}$ |

THERMAL RESISTANCE RATINGS

| Parameter | | Symbol | Typical | Maximum | Unit |
|----------------------------------|------------------------|------------|---------|---------|--------------------|
| Junction-to-Ambient ^b | $t \leq 10\text{ sec}$ | R_{thJA} | 20 | 25 | $^\circ\text{C/W}$ |
| | Steady State | | 62 | 75 | |
| Junction-to-Case | | R_{thJC} | 5 | 6 | |

Notes:

a. See SOA curve for voltage derating.

b. Surface Mounted on 1" x 1" FR-4 board.

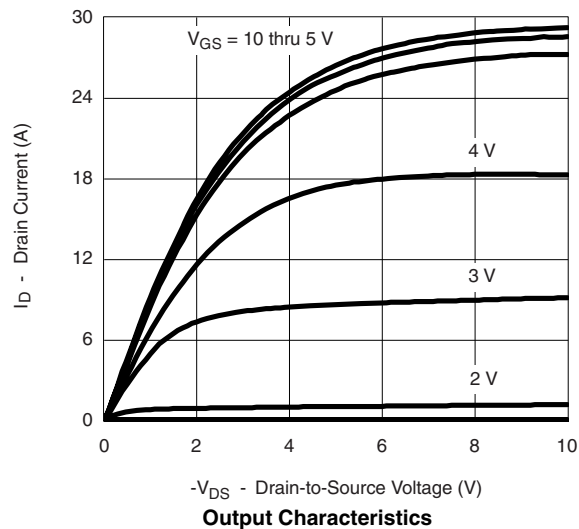
| SPECIFICATIONS $T_J = 25\text{ }^{\circ}\text{C}$, unless otherwise noted | | | | | | |
|--|---------------|--|-------|------------------|-----------|---------------|
| Parameter | Symbol | Test Conditions | Min | Typ ^a | Max | Unit |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$ | - 60 | | | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$ | - 1.0 | - 2.0 | - 3.0 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -60\text{ V}$, $V_{GS} = 0\text{ V}$ | | | - 1 | μA |
| | | $V_{DS} = -60\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 125\text{ }^{\circ}\text{C}$ | | | - 50 | |
| | | $V_{DS} = -60\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 175\text{ }^{\circ}\text{C}$ | | | - 150 | |
| On-State Drain Current ^b | $I_{D(on)}$ | $V_{DS} = -5\text{ V}$, $V_{GS} = -10\text{ V}$ | - 10 | | | A |
| Drain-Source On-State Resistance ^b | $r_{DS(on)}$ | $V_{GS} = -10\text{ V}$, $I_D = -5\text{ A}$ | | 0.061 | | Ω |
| | | $V_{GS} = -10\text{ V}$, $I_D = -5\text{ A}$, $T_J = 125\text{ }^{\circ}\text{C}$ | | 0.100 | | |
| | | $V_{GS} = -10\text{ V}$, $I_D = -5\text{ A}$, $T_J = 175\text{ }^{\circ}\text{C}$ | | 0.150 | | |
| | | $V_{GS} = -4.5\text{ V}$, $I_D = -2\text{ A}$ | | 0.072 | | |
| Forward Transconductance ^b | g_{fs} | $V_{DS} = -15\text{ V}$, $I_D = -5\text{ A}$ | | 8 | | S |
| Dynamic | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = -25\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$ | | 1000 | | pF |
| Output Capacitance | C_{oss} | | | 120 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 100 | | |
| Total Gate Charge | Q_g | $V_{DS} = -30\text{ V}$, $V_{GS} = -10\text{ V}$, $I_D = -8.4\text{ A}$ | | 10 | | nC |
| Gate-Source Charge | Q_{gs} | | | 2.1 | | |
| Gate-Drain Charge | Q_{gd} | | | 3.2 | | |
| Gate Resistance | R_g | $f = 1\text{ MHz}$ | | 8.0 | | Ω |
| Turn-On Delay Time ^c | $t_{d(on)}$ | $V_{DD} = -30\text{ V}$, $R_L = 3.57\text{ }\Omega$ $I_D \cong -8.4\text{ A}$, $V_{GEN} = -10\text{ V}$, $R_G = 2.5\text{ }\Omega$ | | 6 | | ns |
| Rise Time ^c | t_r | | | 15 | | |
| Turn-Off Delay Time ^c | $t_{d(off)}$ | | | 16 | | |
| Fall Time ^c | t_f | | | 8 | | |
| Source-Drain Diode Ratings and Characteristics ($T_C = 25\text{ }^{\circ}\text{C}$) ^b | | | | | | |
| Pulsed Current | I_{SM} | | | | - 30 | A |
| Forward Voltage ^b | V_{SD} | $I_F = -2\text{ A}$, $V_{GS} = 0\text{ V}$ | | - 0.9 | - 1.3 | V |
| Reverse Recovery Time | t_{rr} | $I_F = -8\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$ | | 50 | | ns |
| Reverse Recovery Time | Q_{rr} | | | 80 | | nC |

Notes:

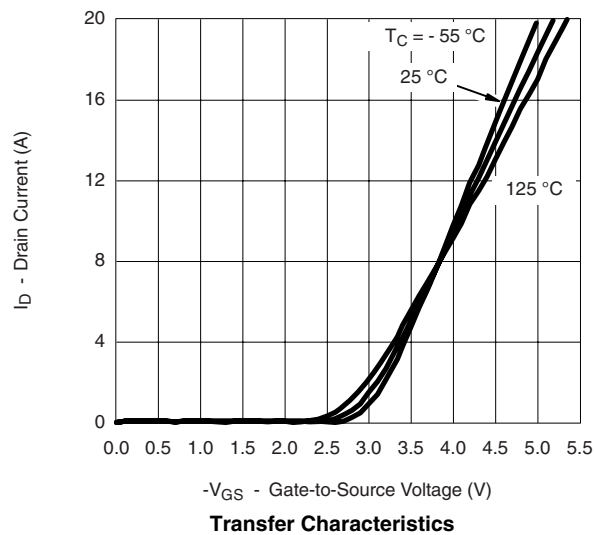
- a. Guaranteed by design, not subject to production testing.
 b. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
 c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C unless noted



Output Characteristics



Transfer Characteristics



Transconductance



On-Resistance vs. Drain Current

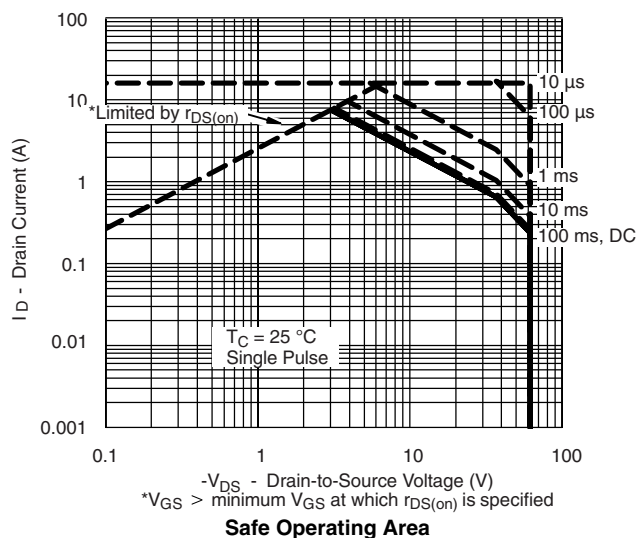


Capacitance



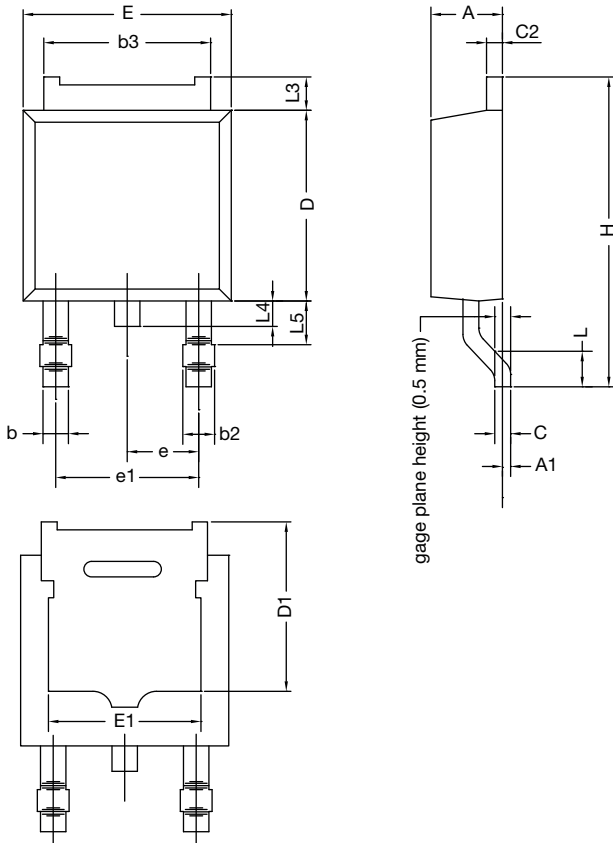
Gate Charge

TYPICAL CHARACTERISTICS 25 °C unless noted

THERMAL RATINGS


THERMAL RATINGS**Normalized Thermal Transient Impedance, Junction-to-Ambient****Normalized Thermal Transient Impedance, Junction-to-Case**

TO-252AA CASE OUTLINE



| DIM. | MILLIMETERS | | INCHES | |
|---------------------------------|-------------|-------|-----------|-------|
| | MIN. | MAX. | MIN. | MAX. |
| A | 2.18 | 2.38 | 0.086 | 0.094 |
| A1 | - | 0.127 | - | 0.005 |
| b | 0.64 | 0.88 | 0.025 | 0.035 |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 |
| C | 0.46 | 0.61 | 0.018 | 0.024 |
| C2 | 0.46 | 0.89 | 0.018 | 0.035 |
| D | 5.97 | 6.22 | 0.235 | 0.245 |
| D1 | 5.21 | - | 0.205 | - |
| E | 6.35 | 6.73 | 0.250 | 0.265 |
| E1 | 4.32 | - | 0.170 | - |
| H | 9.40 | 10.41 | 0.370 | 0.410 |
| e | 2.28 BSC | | 0.090 BSC | |
| e1 | 4.56 BSC | | 0.180 BSC | |
| L | 1.40 | 1.78 | 0.055 | 0.070 |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 |
| L4 | - | 1.02 | - | 0.040 |
| L5 | 1.14 | 1.52 | 0.045 | 0.060 |
| ECN: X12-0247-Rev. M, 24-Dec-12 | | | | |
| DWG: 5347 | | | | |

Note

- Dimension L3 is for reference only.

RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads
Dimensions in Inches/(mm)

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